IN THE CLAIMS:

1. (Currently Amended) A method of manufacturing a display device comprising: ~~, wherein, in the formation of a thin film on an electrode,~~

forming a thin film transistor over a substrate;

forming an electrode which is electrically connected with [[a]] the thin film transistor ~~on a substrate and whose surface is exposed,~~; and

forming a thin film over the electrode with an electron beam evaporation method,

wherein ~~control of~~ an acceleration voltage of electrons of the electron beam evaporation method is ~~performed~~ controlled such that radial rays are not substantially radiated from an evaporation material for forming the thin film[[,]] when [[an]] the evaporation material ~~for forming the thin film~~ is irradiated with an electron beam~~, radial rays are not substantially radiated from the evaporation material~~.

2. (Currently Amended) A method of manufacturing a display device comprising:~~, wherein, in the formation of a thin film on an electrode,~~

forming a thin film transistor over a substrate;

forming an electrode which is electrically connected with [[a]] the thin film transistor ~~on a substrate and whose surface is exposed,~~; and

forming a thin film over the electrode with an electron beam evaporation method,

wherein ~~control of~~ an acceleration voltage of electrons of the electron beam evaporation method is ~~performed~~ controlled such that the thin film transistor is not deteriorated with radial rays radiated from an evaporation material for forming the thin film[[,]] when [[an]] the evaporation material ~~for forming the thin film~~ is irradiated with an electron beam~~, the thin film transistor is not deteriorated with radial rays radiated from the evaporation material~~.

3. (Currently Amended) A method of manufacturing a display device comprising:~~, wherein, in the formation of a light emitter containing an organic compound on a first electrode,~~

forming a thin film transistor over a substrate;

forming a first electrode which is electrically connected with [[a]] the thin film transistor ~~on a substrate and whose surface is exposed,~~;

forming a light emitter containing an organic compound over the first electrode; and

~~and the formation of~~ forming a second electrode [[on]] over the light emitter with an electron beam evaporation method,

wherein ~~control of~~ an acceleration voltage of electrons of the electron beam evaporation method is ~~performed~~ controlled such that radial rays are not substantially radiated from an evaporation material for forming the second electrode[[,]] when [[an]] the evaporation material ~~for forming the second electrode~~ is irradiated with an electron beam~~, radial rays are not substantially radiated from the evaporation material~~.

4. (Currently Amended) A method of manufacturing a display device comprising:~~, wherein, in the formation of a light emitter containing an organic compound on a first electrode,~~

forming a thin film transistor over a substrate;

forming a first electrode which is electrically connected with [[a]] the thin film transistor ~~on a substrate and whose surface is exposed,~~;

forming a light emitter containing an organic compound over the first electrode; and

~~and the formation of~~ forming a second electrode [[on]] over the light emitter with an electron beam evaporation method,

wherein ~~control of~~ an acceleration voltage of electrons of the electron beam evaporation method is ~~performed~~ controlled such that the thin film transistor is not deteriorated with radial rays radiated from the evaporation material for forming the second electrode[[,]] when [[an]] the evaporation material ~~for forming the second electrode~~ is irradiated with an electron beam~~, the thin film transistor is not deteriorated with radial rays radiated from the evaporation material~~.

5. (Currently Amended) A method of manufacturing a display device comprising:~~, wherein, in the formation of a thin film on an electrode,~~

forming a thin film transistor over a substrate;

forming an electrode which is electrically connected with [[a]] the thin film transistor ~~on a substrate and whose surface is exposed,~~; and

forming a thin film over the electrode with an electron beam evaporation method,

wherein control is performed such that~~, when an evaporation material for forming the thin film is irradiated with an electron beam,~~ a time during which[[,]] the thin film transistor is exposed to radial rays radiated from [[the]] an evaporation material for forming the thin film, is shortened with a thickness of the thin film of 0.1 μm or less to thereby avoid deterioration of the thin film transistor when the evaporation material is irradiated with an electron beam.

6. (Currently Amended) A method of manufacturing a display device comprising:~~, wherein, in the formation of a light emitter containing an organic compound on a first electrode,~~

forming a thin film transistor over a substrate;

forming a first electrode which is electrically connected with [[a]] the thin film transistor ~~on a substrate and whose surface is exposed,~~;

forming a light emitter containing an organic compound over the first electrode; and

~~and the formation of~~ forming a second electrode [[on]] over the light emitter with an electron beam evaporation method,

wherein control is performed such that~~, when an evaporation material for forming the thin film is irradiated with an electron beam,~~ a time during which[[,]] the thin film transistor is exposed to radial rays radiated from [[the]] an evaporation material for forming the second electrode, is shortened with a thickness of the ~~thin film~~ second electrode of 0.1 μm or less to thereby avoid deterioration of the thin film transistor when the evaporation material is irradiated with an electron beam.

7. (Original) A method of manufacturing a display device according to claim 1, wherein a multi-component alloy or compound, which is constituted of a metal component and a component containing either or both of alkali metal and alkali earth metal, is used as the evaporation material.

8. (Original) A method of manufacturing a display device according to claim 2, wherein a multi-component alloy or compound, which is constituted of a metal component and a component containing either or both of alkali metal and alkali earth metal, is used as the evaporation material.

9. (Original) A method of manufacturing a display device according to claim 3, wherein a multi-component alloy or compound, which is constituted of a metal component and a component containing either or both of alkali metal and alkali earth metal, is used as the evaporation material.

10. (Original) A method of manufacturing a display device according to claim 4, wherein a multi-component alloy or compound, which is constituted of a metal component and a component containing either or both of alkali metal and alkali earth metal, is used as the evaporation material.

11. (Original) A method of manufacturing a display device according to claim 5, wherein a multi-component alloy or compound, which is constituted of a metal component and a component containing either or both of alkali metal and alkali earth metal, is used as the evaporation material.

12. (Original) A method of manufacturing a display device according to claim 6, wherein a multi-component alloy or compound, which is constituted of a metal component and a component containing either or both of alkali metal and alkali earth metal, is used as the evaporation material.